NSN 5961-00-753-0470

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-753-0470 **Inclosure Material:** Metal **Overall Length:** Between 0.515 inches and 0.565 inches **Overall Diameter:** Between 1.600 inches and 1.650 inches **End Application:** Simulator an/msq-t43 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 0.01 breakover voltage, dc **Current Rating Per Characteristic:** 80.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0